S-Parameters – Introduction (1)

- **Light falling on a car window:**
  - Some parts of the incident light is reflected (you see the mirror image)
  - Another part of the light is transmitted through the window (you can still see inside the car)

- **Optical reflection and transmission coefficients of the window glass define the ratio of reflected and transmitted light**

- **Similar: Scattering (S-) parameters of an *n*-port electrical network (DUT) characterize reflected and transmitted (power) waves**
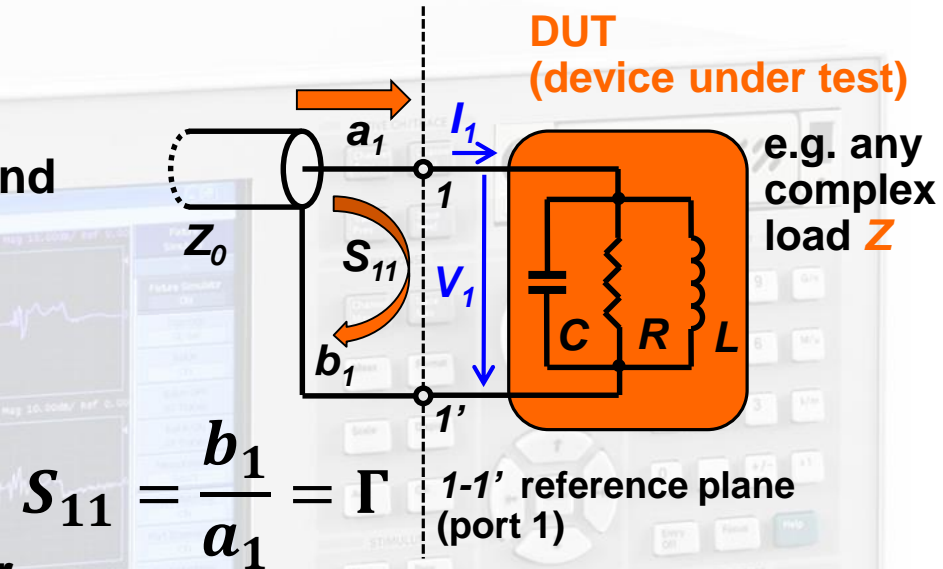
S-Parameters – Introduction (2)

♦ ## Electrical networks

- 1…n-ports circuits
- Defined by **voltages $V_n(\omega)$ or $v_n(t)$** and **currents $I_n(\omega)$ or $i_n(t)$** at the ports
- Characterized by circuit matrices, e.g. ABCD (chain), Z, Y, H, etc.

♦ ## RF networks

- 1…n-port RF DUT circuit or subsystem, e.g. filter, amplifier, transmission-line, hybrid, circulator, resonator, etc.
- Defined by **incident $a_n(\omega, s)$** and **reflected waves $b_n(\omega, s)$** at a **reference plane s (physical position)** at the ports
- Characterized by a scattering parameter (S-parameter) matrix of the reflected and transmitted power waves
- Normalized to a **reference impedance** $\sqrt{Z_0}$ of typically $Z_0 = 50\ \Omega$

DUT (device under test)

e.g. any complex load Z

$$S_{11} = \frac{b_1}{a_1} = \Gamma$$

1-1' reference plane (port 1)

1-port DUT example

♦ **S-Parameters allow to characterize the DUT with the measurement equipment to be located at some distance**

♦ **All high frequency effects of distributed elements are taken into account with respect to the reference plane**

S-Parameters – Example: 2-port DUT
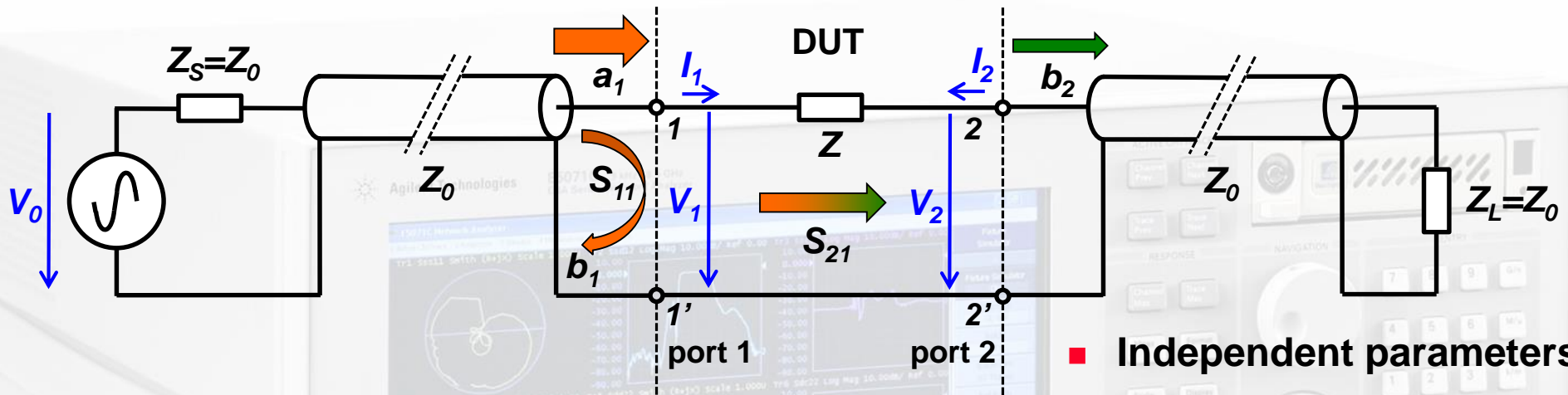
Analysis of the forward S-parameters:

$$S_{11} = \left. \frac{b_1}{a_1} \right|_{a_2=0} \equiv \text{input reflection coefficient}$$

$$(Z_L = Z_0 \Rightarrow a_2 = 0)$$

$$S_{21} = \left. \frac{b_2}{a_1} \right|_{a_2=0} \equiv \text{forward transmission gain}$$

- Examples of 2-ports DUT: filters, amplifiers, attenuators, transmission-lines (cables), etc.
- **ALL ports ALWAYS need to be terminated in their characteristic impedance!**

- **Independent parameters:**

$$a_1 = \frac{V_1^{inc}}{\sqrt{Z_0}} = \frac{V_1 + I_1 Z_0}{2\sqrt{Z_0}}$$

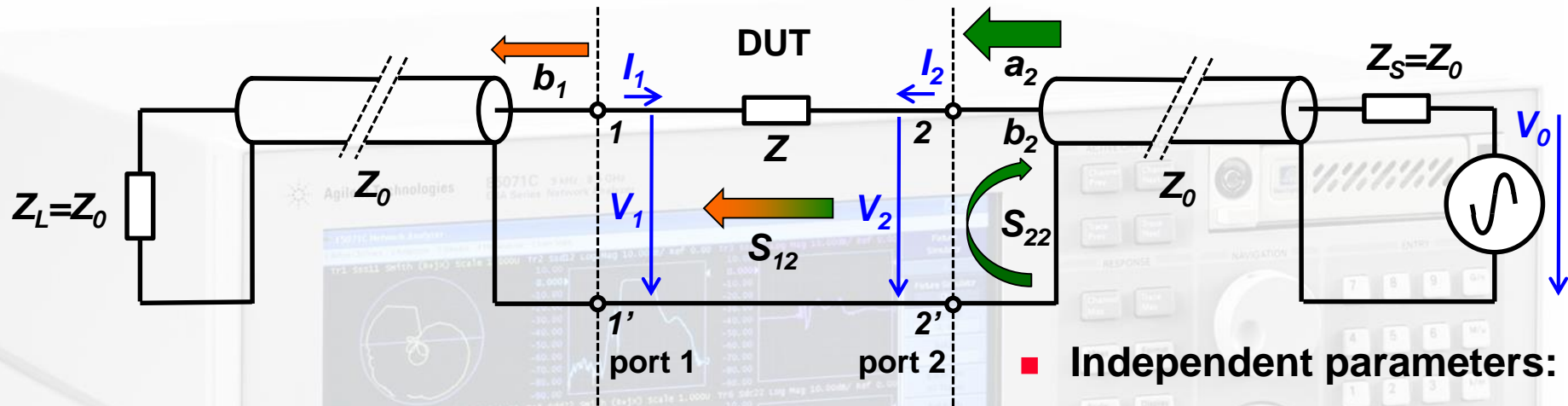$$a_2 = \frac{V_2^{inc}}{\sqrt{Z_0}} = \frac{V_2 + I_2 Z_0}{2\sqrt{Z_0}}$$

- **Dependent parameters:**

$$b_1 = \frac{V_1^{refl}}{\sqrt{Z_0}} = \frac{V_1 - I_1 Z_0}{2\sqrt{Z_0}}$$

$$b_2 = \frac{V_2^{refl}}{\sqrt{Z_0}} = \frac{V_2 - I_2 Z_0}{2\sqrt{Z_0}}$$

S-Parameters – Example: 2-port DUT

♦ **Analysis of the reverse S-parameters:**

$$S_{22} = \left.\frac{b_2}{a_2}\right|_{a_1=0} \equiv \text{output reflection coefficient}$$

$$(Z_L = Z_0 \Rightarrow a_1 = 0)$$

$$S_{12} = \left.\frac{b_1}{a_2}\right|_{a_1=0} \equiv \text{backward transmission gain}$$

■ *n*-port DUTs still can be fully characterized with a 2-port VNA, but again: **don't forget to terminate unused ports!**

■ **Independent parameters:**

$$a_1 = \frac{V_1^{inc}}{\sqrt{Z_0}} = \frac{V_1 + I_1 Z_0}{2\sqrt{Z_0}}$$

$$a_2 = \frac{V_2^{inc}}{\sqrt{Z_0}} = \frac{V_2 + I_2 Z_0}{2\sqrt{Z_0}}$$

■ **Dependent parameters:**

$$b_1 = \frac{V_1^{refl}}{\sqrt{Z_0}} = \frac{V_1 - I_1 Z_0}{2\sqrt{Z_0}}$$

$$b_2 = \frac{V_2^{refl}}{\sqrt{Z_0}} = \frac{V_2 - I_2 Z_0}{2\sqrt{Z_0}}$$

S-Parameters – Definition (1)

- **Linear equations for the 2-port DUT:**

$$b_1 = S_{11}a_1 + S_{12}a_2$$
$$b_2 = S_{21}a_1 + S_{22}a_2$$

- **with:**

$$S_{11} = \frac{b_1}{a_1}\bigg|_{a_2=0} \equiv \text{input reflection coefficient}$$

$$S_{22} = \frac{b_2}{a_2}\bigg|_{a_1=0} \equiv \text{output reflection coefficient}$$

$$S_{21} = \frac{b_2}{a_1}\bigg|_{a_2=0} \equiv \text{forward transmission gain}$$

$$S_{12} = \frac{b_1}{a_2}\bigg|_{a_1=0} \equiv \text{backward transmission gain}$$

S-Parameters – Definition (2)

◆ **Reflection coefficient and impedance at the nth-port of a DUT:**

$$S_{nn} = \frac{b_n}{a_n} = \frac{\frac{V_n}{I_n} - Z_0}{\frac{V_n}{I_n} + Z_0} = \frac{Z_n - Z_0}{Z_n + Z_0} = \Gamma_n$$

$$Z_n = Z_0 \frac{1 + S_{nn}}{1 - S_{nn}} \text{ with } Z_n = \frac{V_n}{I_n} \text{ being the input impedance at the } n^{th} \text{ port}$$

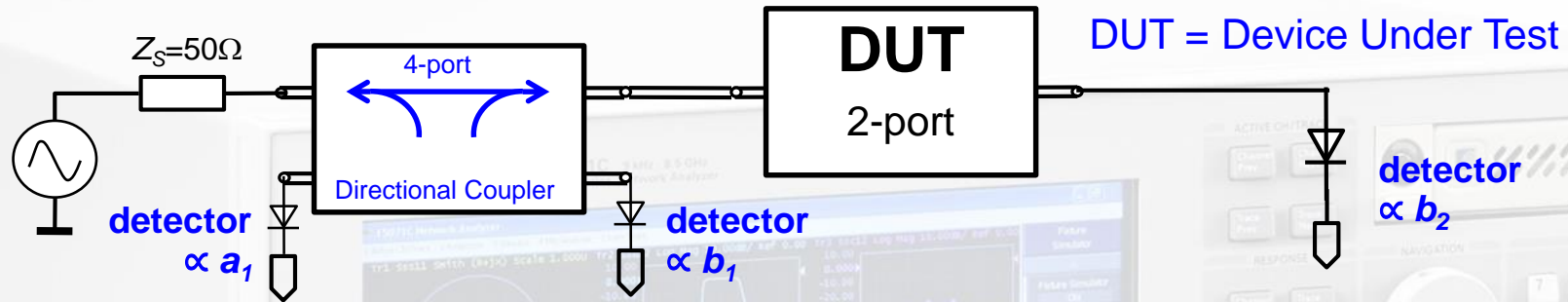◆ **Power reflection and transmission for a n-port DUT**

$$|S_{nn}|^2 = \frac{\text{power reflected from port } n}{\text{power incident on port } n}$$

$$|S_{nm}|^2 = \text{transmitted power between ports } n \text{ and } m$$

with all ports terminated in their characteristic impedance Z_0 and $Z_S = Z_0$

Here the US notion is used, where power = $|a|^2$.
European notation (often): power = $|a|^2/2$
These conventions have no impact on the S-parameters, they are only relevant for absolute power calculations

How to measure S-Parameters?

$Z_S = 50\Omega$

4-port

Directional Coupler

DUT 2-port

DUT = Device Under Test

detector $\propto a_1$

detector $\propto b_1$

detector $\propto b_2$

- ◆ **Performed in the frequency domain**
  - ▪ **Single or swept frequency generator, stand-alone or as part of a VNA or SA**
  - ▪ **Requires a directional coupler and RF detector(s) or receiver(s)**
- ◆ **Evaluate S_{11} and S_{21} of a 2-port DUT**
  - ▪ **Ensure $a_2=0$, i.e. the detector at port 2 offers a well matched impedance**
  - ▪ **Measure incident wave a1 and reflected wave b1 at the directional coupler ports and compute for each frequency**
  - ▪ **Measure transmitted wave b_2 at DUT port 2 and compute**

$$S_{11} = \left.\frac{b_1}{a_1}\right|_{a_2=0}$$

$$S_{21} = \left.\frac{b_2}{a_1}\right|_{a_2=0}$$

- ◆ **Evaluate S_{22} and S_{12} of the 2-port DUT**
  - ▪ **Perform the same methodology as above by exchanging the measurement equipment on the DUT ports**

The *Smith* Chart (1)

◆ **The *Smith* Chart (in impedance coordinates) represents the complex Γ-plane (in polar coordinates) within the unit circle.**

◆ **It is a conformal mapping of the complex Z-plane on the Γ-plane by applying the transformation:**

$$\Gamma = \frac{Z - Z_0}{Z + Z_0}$$
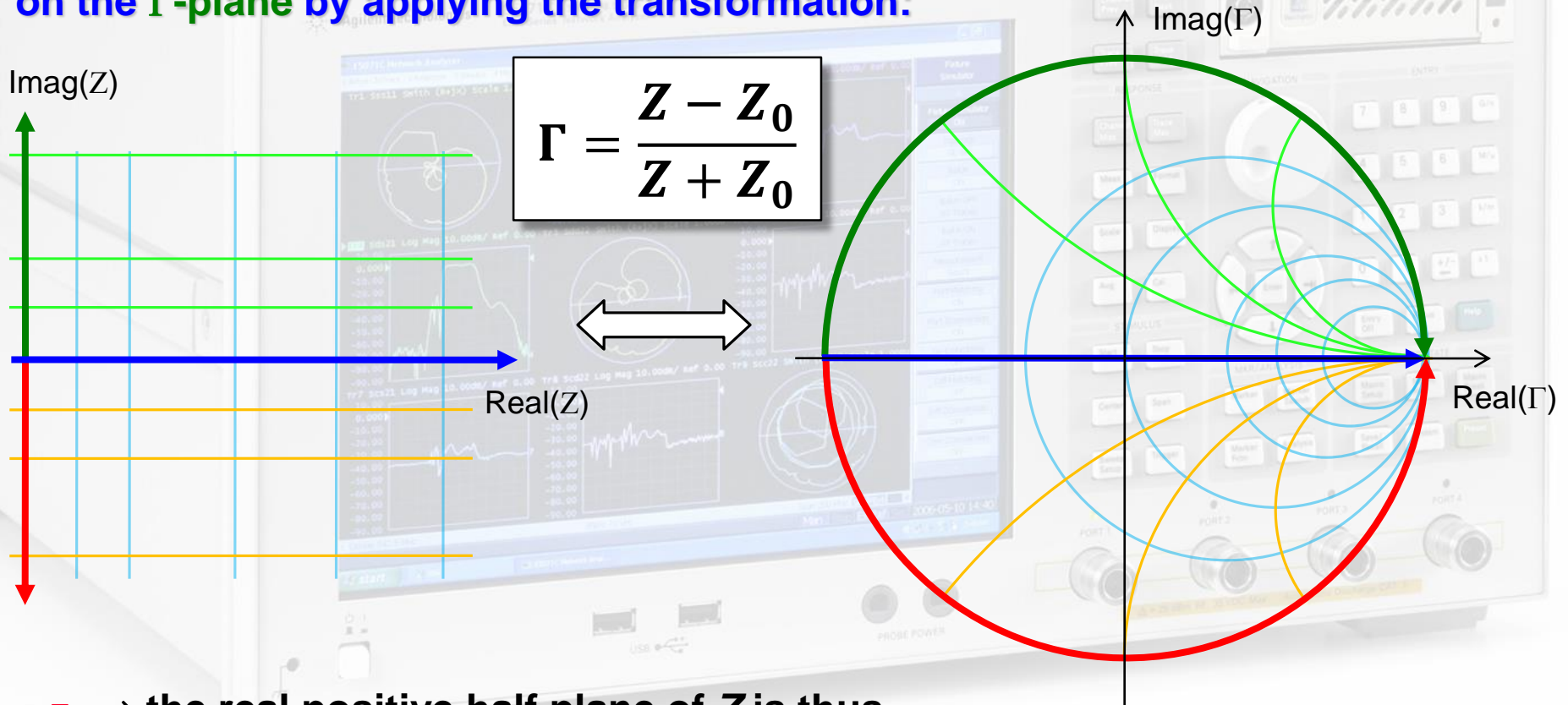
■ **⇒ the real positive half plane of *Z* is thus transformed (*Möbius*) into the interior of the unit circle!**

The *Smith* Chart (2)

- **The Impedance Z is usually normalized** $$z = \frac{Z}{Z_0}$$

  to a reference impedance Z_0,
  typically the characteristic impedance of the coaxial cables of $Z_0=50\Omega$.

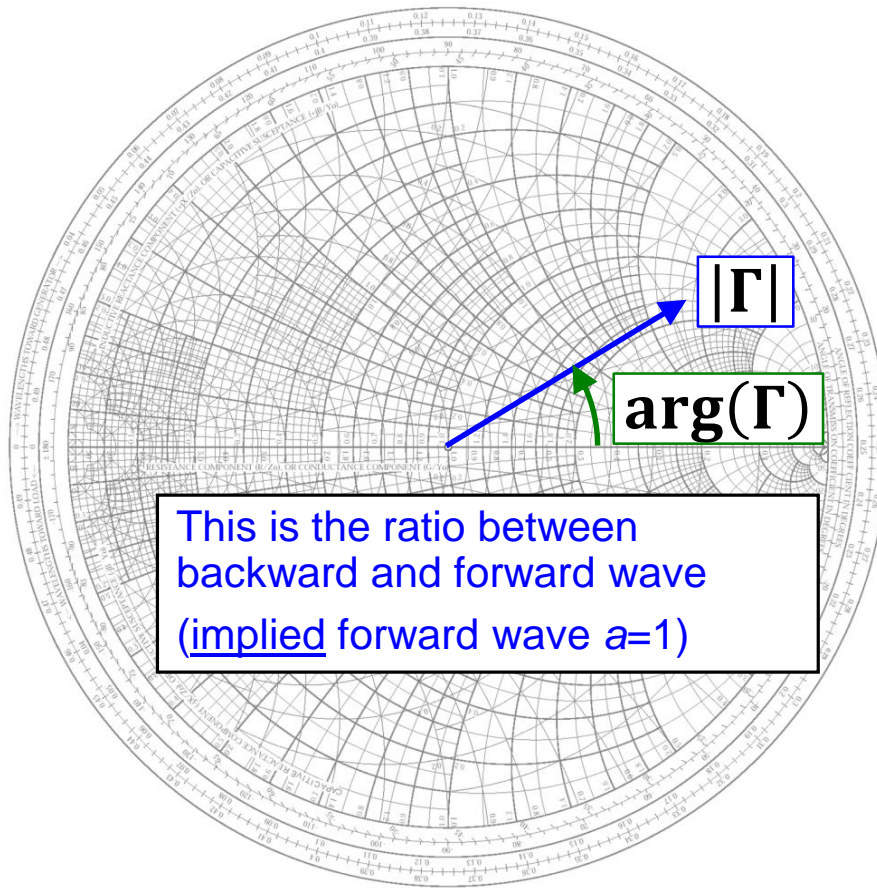- **The normalized form of the transformation follows then as:**

$$\Gamma = \frac{z-1}{z+1} \quad \textbf{resp.} \quad \frac{Z}{Z_0} = z = \frac{1+\Gamma}{1-\Gamma}$$

This mapping offers several practical advantages:

- The diagram includes all "passive" impedances, i.e. those with positive real part, from zero to infinity in a handy format.

  - Impedances with negative real part ("active device", e.g. reflection amplifiers) would be outside the (normal) *Smith* chart.

- The mapping converts impedances or admittances into reflection factors and vice-versa. This is particularly interesting for studies in the radiofrequency and microwave domain where electrical quantities are usually expressed in terms of "incident" or "forward", and "reflected" or "backward" waves.

  - This replaces the notation in terms of currents and voltages used at lower frequencies.

- Also the reference plane can be moved very easily using the *Smith* chart.

The *Smith* Chart (3)

$|\Gamma|$

$\mathbf{arg}(\Gamma)$

This is the ratio between backward and forward wave (<u>implied</u> forward wave *a*=1)

◆ **In the *Smith* chart, the complex reflection factor**

$$\Gamma = |\Gamma|e^{j\varphi} = \frac{b}{a}$$

is expressed in linear cylindrical coordinates, representing the ratio of backward vs. forward traveling waves.
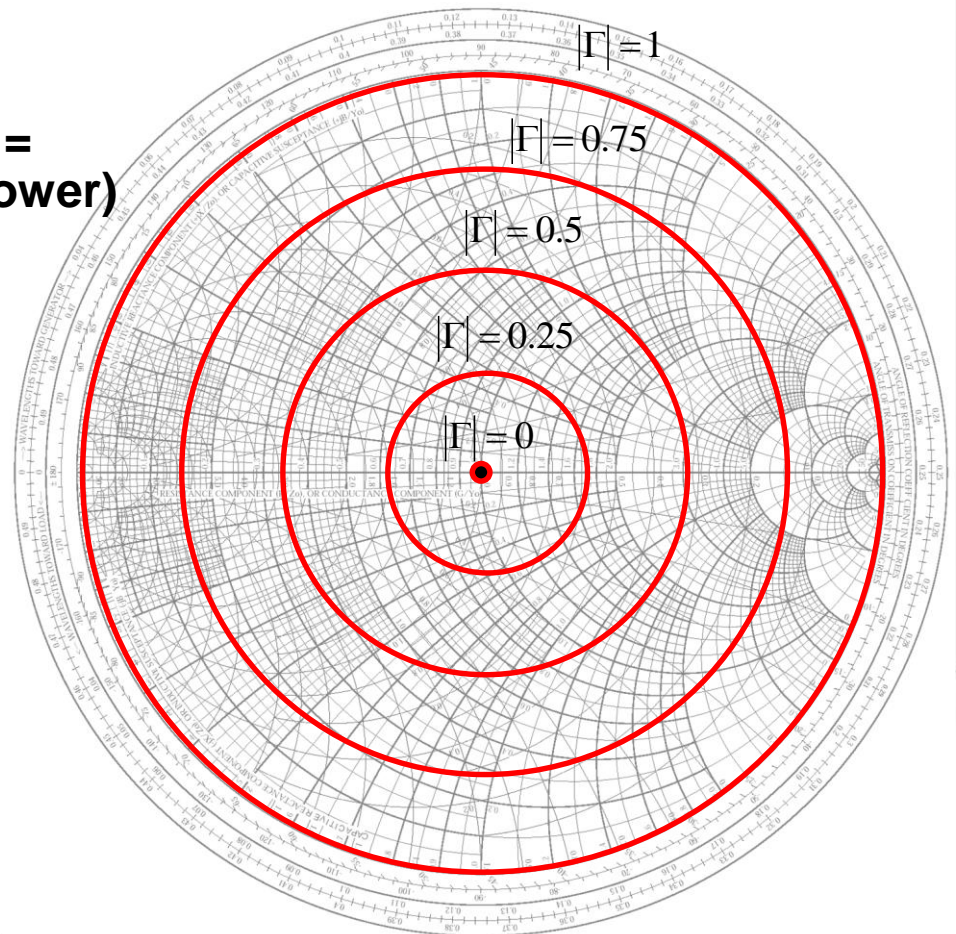
The *Smith* Chart (4)

◆ **The distance from the center of the directly proportional to the magnitude of the reflection factor |Γ|, and permits an easy visualization of the matching performance.**

- **In particular, the perimeter of the diagram represents total reflection: |Γ|=1.**

- **(power dissipated in the load) = (forward power) – (reflected power)**

$$\mathbf{P} = |a|^2 - |b|^2$$
$$= |a|^2\left(1 - |\Gamma|^2\right)$$

available source power

mismatch losses

$|\Gamma| = 1$

$|\Gamma| = 0.75$

$|\Gamma| = 0.5$

$|\Gamma| = 0.25$

$|\Gamma| = 0$

The *Smith* Chart – "Important Points"

Important Points:

- ◆ **Short Circuit**
  Γ = -1, z = 0

- ◆ **Open Circuit**
  Γ = +1, z → ∞

- ◆ **Matched Load**
  Γ = 0, z = 1

- ◆ **On the circle Γ = 1: lossless element**

- ◆ **Upper half: "inductive" = positive imaginary part of Z**

- ◆ **Lower half: "capacitive" = negative imaginary part of Z**

- ▪ **Outside the circle, Γ > 1: active element, for instance tunnel diode reflection amplifier**

Short Circuit

$$z = 0$$
$$\Gamma = -1$$

Im (Γ)

Open Circuit

$$z = \infty$$
$$\Gamma = +1$$

Re(Γ)

$$z = 1$$
$$\Gamma = 0$$

Matched Load